



# Radiation simulations in detector design

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## Introduction

### Simulations of radiation environments

- Long-term immersion in radiation environments can lead to several issues for detector systems
  - Single event effects (e.g., noise occupancy in sensors, bit flips in electronics) can affect integrity of data
  - Radiation damage to sensors and electronics can cause long-term degradation in performance or even complete failure
  - Structural elements can be weakened by prolonged radiation exposure
  - Radioactivation of detector components can affect maintenance procedures
- Simulations of radiation environments can provide an important input in the design of detectors
  - Simulations can be used to mitigate against the effects of radiation damage in sensor components
  - Supplement irradiation tests of detectors + components
- GEANT4 and FLUKA are Monte Carlo software toolkits used for radiation simulations
  - Each simulates the passage of particles through matter
  - Wide range in areas of application, including high energy physics, space science and medical science







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#### Monte Carlo simulations

- Create a model of geometry and material for the full sensor environment, including any surrounding material such as shielding or mounting jigs
  - Material outside the physics acceptance can have a strong influence on the radiation environment through back scattering
  - Important to have correct mass and material composition of each sensor component
  - Trace elements important for radioactivation simulations
- Create a model of the irradiation source
  - Specify type of particles, energy spectrum, geometrical distribution
- Monte Carlo package simulates the transport of the irradiation particles, including any interactions in sensor + surrounding material
  - Many irradiation events are simulated
  - Results are typically averaged over all events to produce average response





## Radiation Resilient Ultrasonic Sensors project



#### **RRUS** project



- Nuclear industry uses ultrasonic testing techniques for non-destructive inspection of safety-critical components in reactors + waste storage units
  - E.g., 1 MGy can correspond to 3 months monitoring of high-level nuclear waste
  - Commercial sensors have limited radiation endurance
- Innovate UK funded two projects to develop radiation resilient ultrasonic sensors robust enough for prolonged use in high-radiation environments
  - **RRUS**: post-operation inspections (mainly gammas)
  - ReDRESS: in-operation monitoring of nuclear reactors (gammas + neutrons)
- The University of Sheffield was responsible for developing a GEANT4 simulation of the sensors + radiation environments
  - Commercial partners (Precision Acoustics, TWI, Ionix) designed + tested prototype sensors



#### Ultrasonic transducers



- High imaging resolution required to monitor, e.g., formation + growth of cracks in components
  - Ultrasonic transducers need to achieve MHz frequencies
- Piezopolymer PVDF (polyvinylidene fluoride) is ideal for high frequency + high bandwidth applications
  - Irradiation of PVDF leads to chain scission, and subsequently cross-linking of polymer chains
  - Results in physical embrittlement of PVDF
  - Difficult to improve innate radiation resilience of PVDF
- COTS (Conventional Off-The-Shelf) transducers typically use epoxy resin as an adhesive agent
  - Gamma irradiation of epoxy leads to formation of gasses
  - Extended radiation exposure can cause build-up of gas pressure, stresses within the material







#### RRUS transducer design



- Precision Acoustics designed + fabricated transducers with stainless-steel housing
  - Also trialled tungsten alloy housing
- 20-mm acoustic delay line acts as radiation shield for the PVDF film
- All components designed to screw together mechanically via threaded sections
  - Assembled with torque wrench to counter pressures from radiolytic gas production in epoxy
  - No reliance on adhesive bonds





#### DCF Co-60 irradiator simulation



- Prototype probes were irradiated for 14 days during August 2018 with Cobalt-60 source at The University of Manchester's Dalton Cumbrian Facility (DCF)
  - Co-60 emits mainly gamma rays with energies 1.17 & 1.33 MeV
- Developed simulation of Co-60 irradiation chamber
  - Important to understand radiation environment inside chamber + dose profiles within devices under test
- Simulation predictions were benchmarked with dose rate measurements taken in empty chamber
  - Generally good agreement; variation typically less than 30%
  - Gives confidence in simulation predictions for probe irradiation test
- Importance of including steel chamber walls in simulation shown by previous version without walls
  - Back scattering from walls increases dose rates







#### RRUS irradiation at DCF



- Simulated the test setup used in DCF irradiation
  - Highlighted three prototype probes (PVDF thicknesses 52um, 40um, 110um) + COTS probe
  - Nine Cobalt-60 rods also visible
- Side projection of energy deposited
  - Probes and test stand clearly visible

- Front view of dose at front face of probes
  - Dose highest along central axis of chamber
  - Decreases towards sides of chamber









#### Dose profiles in probes



- For probe located along central axis (SS110um), no horizontal asymmetry in dose profile
- For probe located off central axis (SS40um), clear horizontal asymmetry in dose profile
  - Dose higher towards centre of chamber
- Dose values at front face of probe and at PVDF obtained from dose profiles
  - Dose at PVDF reduced due to shielding effect of delay line

Probe	Dose at front [MGy]	Dose at PVDF [MGy]	Ratio PVDF/front
SS52um	7.27	3.87	0.53
SS40um	7.15	3.83	0.54
SS110um	10.46	4.47	0.43







#### Irradiation results



- Probes were irradiated up to maximum cumulative gamma dose of 10.5 MGy; corresponds to 4 MGy at PVDF
  - Previous literature up to 1 MGy
- New shielded probe designs more resilient to radiation than COTS design
  - COTS PVDF delaminated from backing material, showed high levels of embrittlement
  - New designs showed no signs of severe degradation
- Probe performance improved up to ~500 kGy
  - Radiation-induced chain scission increases dipole moment of PVDF
  - Beyond 500 kGy, increased crosslinking leads to stiffening of PVDF
- Results published in Nondestructive Testing and Evaluation, Volume 35, Issue 2
  - In situ monitoring of PVDF ultrasound transducers under gamma irradiation







#### Post-irradiation probe operation



- Irradiated probe was used to scan steel test block with a FBH (flat bottom hole) defect at 15mm depth
  - Defect is clearly visible in scan
  - Demonstrates that probes remain functional postirradiation





#### Shielding design study



- Studied impact of varying the length of stainless steel delay line
  - Simulated large planar source of cesium-137 and strontium-90 in front of delay line
  - Cs-137 and Sr-90 (+ daughters) are dominant isotopes in high-level waste (NDA 2016 waste inventory)
- Compared with dose ratio calculated from attenuation coefficient for steel (0.426 cm<sup>-1</sup>); corresponds to radiation entering solely through the front face
  - As delay line length increases, ratio from simulation decreases more slowly than ratio from attenuation calculation
  - Radiation entering from side of probe increasingly significant relative to radiation entering from front

	Shielding length [mm]	Ratio PVDF/front from simulation	Ratio PVDF/front from attenuation calculation
	10	0.63	0.65
	20 (baseline)	0.49	0.43
	30	0.36	0.28
Paul S Miya	40	0.29	0.18







#### RRUS commercialisation



 Based on success of RRUS project, Precision Acoustics are marketing radiation resilient ultrasonic transducers







## ATLAS Upgrade project



### ATLAS Upgrade project

- Starting in 2025, the LHC will be upgraded to the High-Luminosity Large Hadron Collider (HL-LHC)
  - HL-LHC will deliver a fivefold increase in instantaneous luminosity, tenfold increase in integrated luminosity
- At the same time, ATLAS will install a number of Phase-II Upgrade subdetectors
  - Current Inner Detector (ID) will be replaced by an allsilicon Inner Tracker (ITk)
  - High Granularity Timing Detector (HGTD) to be installed between ITk and endcap calorimeter
  - Electronics upgrades for calorimeter and muon systems







- Inelastic hadron-hadron collisions are dominated by soft (low-p<sub>T</sub>) interactions
  - These events are selected for study by the minimum bias trigger
  - Main source of radiation backgrounds; particularly intense in high-eta regions
- Numerous challenges posed by radiation backgrounds for design of Inner Tracker
  - Radiation exposure lifetime for ITk will be increased tenfold compared to ID
    - Luminosity of 4000 fb<sup>-1</sup> for HL-LHC running; cf LHC luminosity 350 fb<sup>-1</sup>
  - ITk silicon sensors will be placed closer to regions of greater radiation intensity
    - ITk eta coverage extended to 4; cf ID eta coverage to 2.5
  - Back scattering of neutrons from calorimeters
    - Polyethylene shielding to moderate neutrons
    - HGTD also potential source of back scattering; designed to mitigate impact on ITk



ATLAS Run-2 Inner Detector



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PPRC seminar, 18 June 2020



### Radiation damage in silicon sensors

- Most significant radiation-induced damage in a silicon lattice is Non-Ionising Energy Loss (NIEL)
  - Radiation displaces lattice atoms, creates bulk defects
  - Concentration of bulk defects increases with time
- Bulk defects introduce new energy levels in the band gap
  - Close to conduction or valence band: acts as donor or acceptor, changes effective doping concentration
    - NB: Deliberate doping can produce desired defects
  - Shallow levels: traps electrons + holes, reduces charge collection efficiency (CCE)
  - Close to mid-gap: increases generation of leakage currents
- Annealing increases mobility of defect atoms
  - Can be used to reduce concentration of bulk defects, recover sensor performance



acceptor

Shockley-Read Hall statistics

, standard theory nter-center charg

transfer model

inside clusters only enhanced after diffusion - annealing



Silicon damage fluence



 $\overline{\mathbf{S}}$ 

- Silicon damage (1 MeV) fluence  $\Phi_{eq}$  is a proxy for NIEL in silicon
  - Used to model evolution of leakage currents + depletion voltages, which allow us to anticipate detector performance over its lifetime
  - Commonly scored in radiation simulations
- Silicon damage fluences calculated by weighting particle of particular type + energy with silicon damage factors
  - Damage factors scale to equivalent of 1 MeV neutron in silicon
  - Damage factors are combination of test beam data + calculations from nuclear interaction models
    ATLAS Simulation Prelimin





#### ATLAS radiation simulations



- Bulk of ATLAS radiation simulation work done with FLUKA
  - FLUKA also used by other LHC experiments + CERN Radiation Protection (RP)
  - ATLAS previously also used FLUGG and GCALOR
  - GEANT4 being used increasingly for radiation simulations
  - Different MC codes enable mutual cross-check
- Standalone FLUKA model with simplified version of full ATLAS detector geometry and material (including calorimeters, shielding, beam line)
  - Different detector layouts can be implemented + studied relatively quickly (compared to full ATLAS GEANT4 simulation for physics)
  - Simplified geometry cannot accommodate detailed physics studies
  - Same FLUKA model used for radioactivation calculations by CERN RP
  - Minimum-bias events for proton-proton collisions used as input
- Other commonly scored quantities in radiation simulations
  - **Ionising dose** important for predicting damage in electronics
  - Fluence of hadrons > 20 MeV to estimate rate of Single Event Effects in electronics
  - Charged particle fluence to estimate occupancies + data rates
  - Radioactivation estimates can dictate procedures for cavern access and detector installation + maintenance



### Benchmarking of Run-2 results



- Leakage currents are an inherent feature of silicon sensors
  - Silicon sensors are doped to produce p-n junctions
  - Differences in doping concentration result in electric field across the depletion zone of the p-n junction
  - Thermally generated charge carriers will drift in this field, leading to leakage current
- Leakage current models (e.g., Sheffield-Harper) predict evolution of these currents over lifetime of detector

 $I(t, \mathbf{T}, \Phi_{eq}) = I_0 + \alpha(t, \mathbf{T}) \Phi_{eq} V$ 

- Fluence predictions  $\Phi_{\rm eq}$  feed into leakage current model
- Temperature annealing effects also included
- Comparison of predictions with leakage current measurements gives good agreement
  - Other benchmarking comparisons with Radiation Monitor measurements also give good agreement
  - Gives confidence in radiation simulation predictions for Upgrade scenarios







#### Upgrade detector studies



- Fluence predictions for Upgrade detector updated as ITk layout evolves
  - Radiation simulations provide feedback link between physicists and engineers
  - Latest published results: <u>Pixel TDR</u>, June 2018
  - Many other alternative layouts studied, not published
  - Latest ITk layout still evolving with latest engineering designs + trigger schemes
- Maximum fluence values in ITk regions used for irradiation tests of sensors + chips
- Other dedicated studies on particular topics
  - Particle contribution to silicon damage fluences
  - Impact of placement of services on fluences in ITk and downstream subdetectors
  - HGTD shielding design
  - Comparison of GEANT4 with FLUKA for radiation simulations





r [cm]

z [cm]



#### LHC radiation effects workshops



- Series of workshops devoted to discussing effects of radiation on performance of LHC detectors
  - <u>31<sup>st</sup> RD50 workshop</u>, November 2017
  - <u>1<sup>st</sup> workshop on radiation effects in the LHC experiments</u>, April 2018
  - 2<sup>nd</sup> workshop on radiation effects in the LHC experiments, February 2019
  - CERN Yellow Report in preparation







## Summary



Summary



- Long-term exposure to radiation environments can lead to performance degradation in detector systems
  - Simulations of radiation environments can provide an important input in detector design to mitigate such issues
- Role of radiation simulations in Radiation Resilient Ultrasonic Sensors (RRUS) project
  - Full simulation of DCF irradiation test provided accurate dosimetry in PVDF sensor material
  - Simulation studies of shielding design to mitigate against effects of radiation
- Role of radiation simulations in ATLAS Upgrade project
  - Provide feedback link between physicists and engineers in design of the Upgrade detector
  - Dedicated studies to optimise detector layout and thereby reduce radiation levels in critical regions
  - Predictions of radiation levels facilitate modelling of detector performance evolution